

GaAs MMIC SPST TERMINATED SWITCH, DC - 4GHz

Features

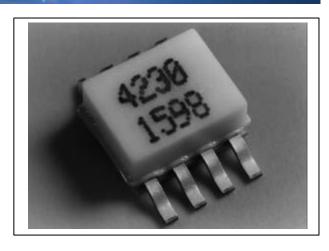
Broadband performance

• Low insertion loss; 1.8dB typ at 2GHz

• Ultra low DC power consumption

• Fast switching speed; 3ns typical

SO8 surface mount ceramic package



Description

The P35-4230-C06-200 is a high performance Gallium Arsenide single pole singe throw broadband RF switch. It is suitable for use in broadband communications and instrumentation applications. A 50Ω termination is presented at the isolated output of the switch. Control is effected by the application of complimentary 0V and -5V levels to the control lines in accordance with the truth table below.

This die is fabricated using MCL's $0.5\mu m$ gate length MESFET process (S20) and is fully protected using Silicon Nitride passivation for excellent performance and reliability. This device is packaged in a ceramic package.

Electrical Performance

Ambient temperature = 22 ± 3 °C , Z_0 = $50\,\Omega$, Control voltages = 0V/-5V unless otherwise stated

Parameter	Conditions	Min	Тур	Max	Units
Insertion Loss	DC - 2GHz	-	1.8	2.0	dB
_	2 - 4GHz	-	2.2	3.0	dB
Isolation	DC - 2GHz	30	35	-	dB
	2 - 4GHz	25	30	-	dB
Input Return Loss¹	DC - 2GHz	10	11	-	dB
	2 - 4GHz	8	10	-	dB
Output Return Loss¹	DC - 2GHz	10	11	-	dB
	2 - 4GHz	8	10	-	dB
1dB power compression point ²	0/-5V Control; 2GHz	-	23	-	dBm
	0/-8V Control; 2GHz	-	30	-	dBm
Switching Speed	50% Control to 10%90%RF	-	3	-	ns

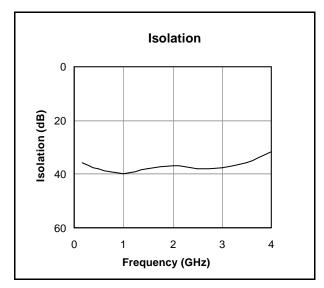
Notes

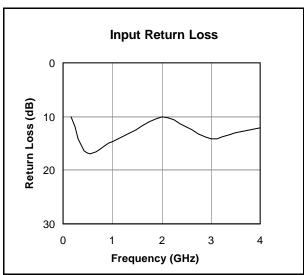
- 1. Return Loss measured in low loss switch state.
- 2. Input power at which insertion loss compresses by 1dB.

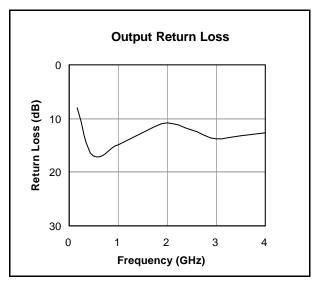


Typical Performance at 22° C







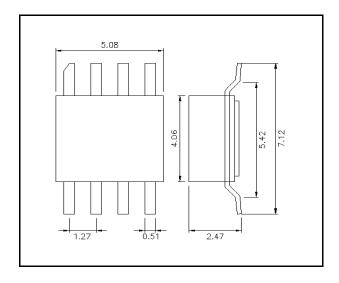


Absolute Maximum Ratings

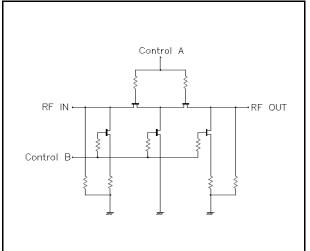
 $\begin{array}{lll} \text{Max control voltage} & -8V \\ \text{Max I/P power} & +33 \text{ dBm} \\ \text{Operating temperature} & -40^{\circ}\text{C to } +85^{\circ}\text{C} \\ \text{Storage temperature} & -65^{\circ}\text{C to } +150^{\circ}\text{C} \\ \end{array}$



Package Outline



Electrical Schematic



Pin Description

Pin	Function	
1	Ground	
2	Control A	
3	Control B	
4	Ground	
5	RF IN	
6	Ground	
7	Ground	
8	RF OUT	

Switching Diagram

A	В	RF IN-RF OUT
0V	-5V	Low loss
-5V	0V	Isolated

Ordering Information

P35-4230-C06-200